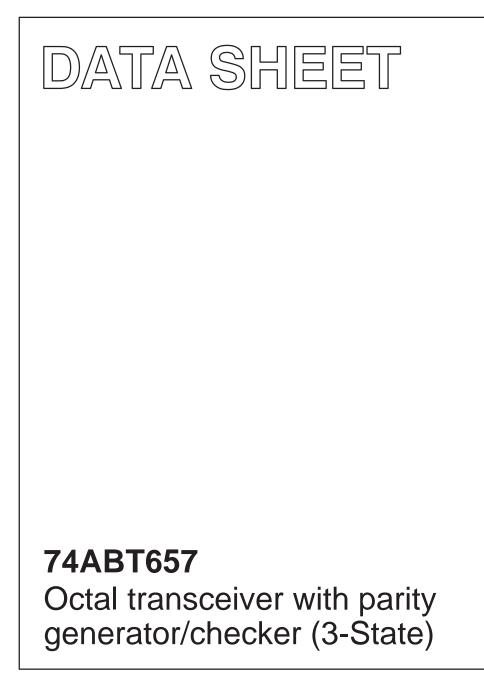
INTEGRATED CIRCUITS



Product data sheet Supersedes data of 1995 Dec 11 2004 Oct 27



Philips Semiconductors

74ABT657

FEATURES

- Combinational functions in one package
- Low static and dynamic power dissipation with high speed and high output drive
- Output capability: +64 mA/-32 mA
- Power-up 3-State
- Latch-up protection exceeds 500 mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

DESCRIPTION

The 74ABT657 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT657 is an octal transceiver featuring non-inverting buffers with 3-State outputs and an 8-bit parity generator/checker, and is intended for bus-oriented applications. The buffers have a guaranteed current sinking capability of 64 mA. The Transmit/Receive (T/\overline{R}) input determines the direction of the data

flow through the bidirectional transceivers. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B ports to A ports. The Output Enable (OE) input disables both the A and B ports by placing them in a high-impedance condition when the OE input is HIGH. The parity select (ODD/EVEN) input gives the user the option of odd or even parity systems. The parity (PARITY) pin is an output from the generator/checker when transmitting from the port A to B $(T/\overline{R} = HIGH)$ and an input when receiving from port B to A port (T/\overline{R}) = Low). When transmitting (T/R = HIGH) the parity select (ODD/EVEN) input is set, then the A port data is polled to determine the number of HIGH bits. The parity (PARITY) output then goes to the logic state determined by the parity select (ODD/EVEN) setting and by the number of HIGH bits on port A. For example, if the parity select (ODD/EVEN) is set LOW (even parity), and the number of HIGH bits on port A is odd, then the parity (PARITY) output will be HIGH, transmitting even parity. If the number of HIGH bits on port A is even, then the parity (PARITY) output will be LOW, keeping even parity. When in receive mode (T/ \overline{R} = LOW) the B port is polled to determine the number of HIGH bits. If parity select (ODD/EVEN) is LOW (even parity) and the number of HIGHs on port B is:

- (1) odd and the parity (PARITY) input is HIGH, then ERROR will be HIGH, signifying no error.
- (2) even and the parity (PARITY) input is HIGH, then ERROR will be asserted LOW, indicating an error.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25 °C; GND = 0 V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	C _L = 50 pF; V _{CC} = 5 V	3.3	ns
C _{IN}	Input capacitance	$V_{I} = 0 V \text{ or } V_{CC}$	4	pF
C _{I/O}	I/O capacitance	Outputs disabled; $V_O = 0 V \text{ or } V_{CC}$	7	pF
I _{CCZ}	Total supply current	Outputs disabled; V_{CC} =5.5 V	500	nA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
24-Pin plastic SO	–40 °C to +85 °C	74ABT657D	SOT137-1
24-Pin Plastic SSOP Type II	–40 °C to +85 °C	74ABT657DB	SOT340-1
24-Pin Plastic DIP	–40 °C to +85 °C	74ABT657N	SOT222-1
24-Pin Plastic TSSOP Type I	–40 °C to +85 °C	74ABT657PW	SOT355-1

PIN CONFIGURATION

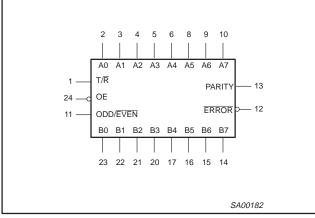
		1
T/R 1	$\mathbf{\circ}$	24 OE
A0 2		23 во
A1 3		22 B1
A2 4		21 B2
A3 5		20 ВЗ
A4 6		19 GND
V _{CC} 7	TOP VIEW	18 GND
A5 8		17 B4
A6 9		16 B5
A7 10		15 B6
ODD/EVEN 11		14 в7
ERROR 12		13 PARITY
		SA00181

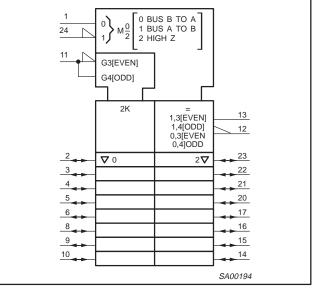
PIN DESCRIPTION

SYMBOL	PIN NUMBER	NAME AND FUNCTION
13	PARITY	Parity output
11	ODD/EVEN	Parity select input
12	ERROR	Error output
1	T/R	Transmit/receive input
2, 3, 4, 5, 6, 8, 9, 10	A0 to A7	A port 3-State outputs
23, 22, 21, 20, 17, 16, 15, 14	B0 to B7	B port 3-State outputs
24	ŌĒ	Output enable input (active-LOW)
18, 19	GND	Ground (0 V)
7	V _{CC}	Positive supply voltage

74ABT657

LOGIC SYMBOL





FUNCTION TABLE

NUMBER OF HIGH INPUTS		INPUTS	i	INPUT/ OUTPUT	OUTPUTS	
	OE	T/R	ODD/EVEN	PARITY	ERROR	OUTPUTS MODE
	L	Н	Н	Н	Z	Transmit
	L	н	L	L	Z	Transmit
0, 2, 4, 6, 8	L	L	Н	н	Н	Receive
0, 2, 4, 0, 0	L	L	н	L	L	Receive
	L	L	L	н	L	Receive
	L	L	L	L	Н	Receive
	L	Н	Н	L	Z	Transmit
	L	н	L	н	Z	Transmit
1 2 5 7	L	L	н	н	L	Receive
1, 3, 5, 7	L	L	Н	L	Н	Receive
	L	L	L	н	Н	Receive
	L	L	L	L	L	Receive
Don't care	Н	Х	Х	Z	Z	3-State

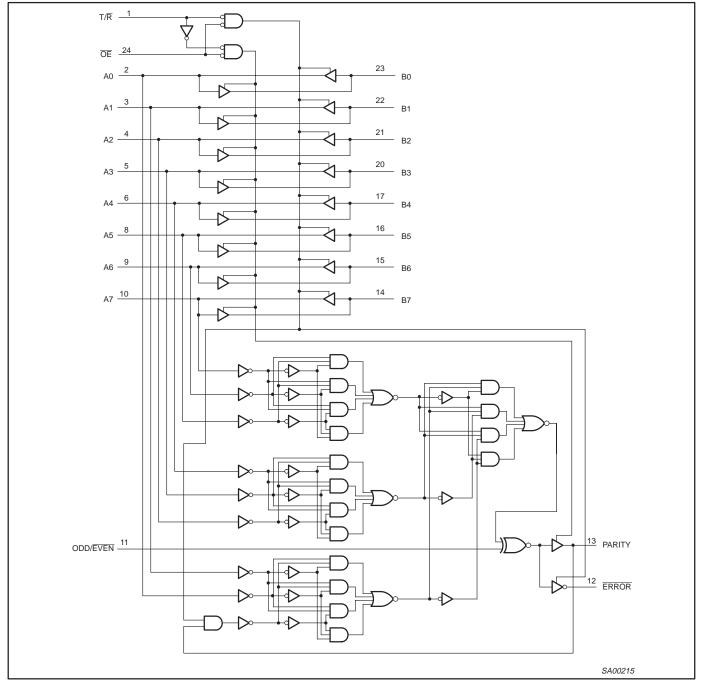
H = HIGH voltage level L = LOW voltage level

X = Don't care Z = High-impedance "off" state

LOGIC SYMBOL (IEEE/IEC)

74ABT657

LOGIC DIAGRAM



74ABT657

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V ₁ < 0 V	-18	mA
VI	DC input voltage ³		-1.2 to +7.0	V
I _{ОК}	DC output diode current	V _O < 0 V	-50	mA
V _{OUT}	DC output voltage ³	output in Off or HIGH state	-0.5 to +5.5	V
I _{OUT}	DC output current	output in LOW state	128	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction

temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C. 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT		
STWBUL	PARAMETER	Min	Max		
V _{CC}	DC supply voltage	4.5	5.5	V	
VI	Input voltage	0	V _{CC}	V	
V _{IH}	HIGH-level input voltage	2.0		V	
VIL	LOW-level input voltage		0.8	V	
I _{OH}	HIGH-level output current		-32	mA	
I _{OL}	LOW-level output current		64	mA	
$\Delta t/\Delta v$	Input transition rise or fall rate	0	5	ns/V	
T _{amb}	Operating free-air temperature range	-40	+85	°C	

Product data sheet

74ABT657

DC ELECTRICAL CHARACTERISTICS

						LIMITS			
SYMBOL	SYMBOL PARAMETER		PARAMETER TEST CONDITIONS		T _{amb} = +25 ℃			–40 °C 35 °C	UNIT
				Min	Тур	Max	Min	Max	
V _{IK}	Input clamp volt	age	$V_{CC} = 4.5 \text{ V}; \text{ I}_{IK} = -18 \text{ mA}$		-0.9	-1.2		-1.2	V
			V_{CC} = 4.5 V; I_{OH} = –3 mA; V_{I} = V_{IL} or V_{IH}	2.5	3.5		2.5		V
V _{OH}	HIGH-level outp	out voltage	V_{CC} = 5.0 V; I_{OH} = -3 mA; V_I = V_{IL} or V_{IH}	3.0	4.0		3.0		V
			V_{CC} = 4.5 V; I_{OH} = -32 mA; V_I = V_{IL} or V_{IH}	2.0	2.6		2.0		V
V _{OL}	LOW-level outp	ut voltage	V_{CC} = 4.5 V; I_{OL} = 64 mA; V_I = V_{IL} or V_{IH}		0.42	0.55		0.55	V
L.	Input leakage	Control pins	V_{CC} = 5.5 V; V_{I} = GND or 5.5 V		±0.01	±1.0		±1.0	μΑ
łı	current	Data pins	V_{CC} = 5.5 V; V_I = GND or 5.5 V		±5	±100		±100	μΑ
I _{OFF}	Power-off leaka	ge current	V_{CC} = 0 V; V_O or V_I \leq 4.5 V		±5.0	±100		±100	μΑ
I _{PU} I _{PD}	Power-up/down 3-State output current ³		$V_{CC} = 2.0 \text{ V}; V_0 = 0.5 \text{ V}; V_1 = \text{GND or } V_{CC};$ $V_{OE} = V_{CC}$		±5.0	±50		±50	μΑ
I _{IH} + I _{OZH}	3-State output H	HGH current	V_{CC} = 5.5 V; V_{O} = 2.7 V; V_{I} = V_{IL} or V_{IH}		5.0	50		50	μΑ
I _{IL} + I _{OZL}	3-State output L	OW current	V_{CC} = 5.5 V; V_{O} = 0.5 V; V_{I} = V_{IL} or V_{IH}		-5.0	-50		-50	μΑ
I _{CEX}	Output HIGH lea	akage current	V_{CC} = 5.5 V; V_{O} = 5.5 V; V_{I} = GND or V_{CC}		5.0	50		50	μΑ
Ι _Ο	Output current ¹		$V_{CC} = 5.5 \text{ V}; V_{O} = 2.5 \text{ V}$	-50	-80	-180	-50	-180	mA
I _{ССН}			V_{CC} = 5.5 V; Outputs HIGH; V _I = GND or V _{CC}		0.5	250		250	μΑ
I _{CCL}	Quiescent supp	ly current	V_{CC} = 5.5 V; Outputs LOW; V _I = GND or V _{CC}		20	30		30	mA
I _{CCZ}			V_{CC} = 5.5 V; Outputs 3-State; V _I = GND or V _{CC}		0.5	250		250	μΑ
			Outputs enabled, one data input at 3.4 V, other inputs at V _{CC} or GND; V _{CC} = 5.5 V		0.5	1.5		1.5	mA
ΔI_{CC}	Additional suppl input pin ²	y current per	Outputs 3-State, one data input at 3.4 V, other inputs at V _{CC} or GND; V _{CC} = 5.5 V		50	250		250	μA
			Outputs 3-State, one enable input at 3.4 V, other inputs at V _{CC} or GND; V _{CC} = 5.5 V		0.5	1.5		1.5	mA

NOTES:

Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
 This is the increase in supply current for each input at 3.4 V.
 This parameter is valid for any V_{CC} between 0 V and 2.1 V with a transition time of up to 10 msec. For V_{CC} = 2.1 V to V_{CC} = 5 V ± 10 %, a transition time of up to 100 µsec is permitted.

Product data sheet

74ABT657

AC CHARACTERISTICS

GND = 0 V; $t_R = t_F$ = 2.5 ns; C_L = 50 pF, R_L = 500 Ω

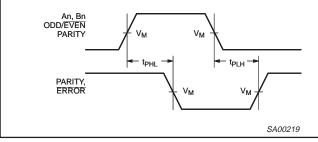
					LIMITS			
SYMBOL	PARAMETER	WAVEFORMS	-	Γ _{amb} = +25 ° V _{CC} = +5.0 \	C /	T _{amb} = -40 V _{CC} = +5.	°C to +85 °C 0 V ± 10 %	UNIT
			Min	Тур	Max	Min	Max	
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	2	1.1 1.2	2.5 3.0	4.1 3.9	1.1 1.2	4.6 4.3	ns
t _{PLH} t _{PHL}	Propagation delay An to PARITY	1, 2	2.5 2.8	5.1 5.0	6.7 7.4	2.5 2.8	8.1 8.9	ns
t _{PLH} t _{PHL}	Propagation delay ODD/EVEN to PARITY, ERROR	1, 2	1.7 1.9	3.5 3.7	4.6 5.1	1.7 1.9	5.3 5.8	ns
t _{PLH} t _{PHL}	Propagation delay Bn to ERROR	1, 2	3.9 4.0	7.3 7.9	10.2 10.5	3.9 4.0	12.3 12.9	ns
t _{PLH} t _{PHL}	Propagation delay PARITY to ERROR	1, 2	2.7 3.2	4.5 5.2	5.9 6.7	2.7 3.2	7.7 8.1	ns
t _{PZH} t _{PZL}	Output enable time ¹ to HIGH or LOW level	3, 4	1.3 1.9	3.6 4.2	5.5 5.3	1.3 1.9	6.5 6.5	ns
t _{PHZ} t _{PLZ}	Output disable time from HIGH or LOW level	3, 4	2.4 2.2	3.6 3.4	5.6 7.3	2.4 2.2	6.2 7.8	ns

NOTES:

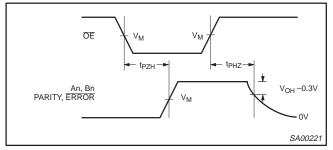
These delay times reflect the 3-State recovery time only and do not include the delay through the buffers and the parity check circuitry which affect the ERROR output. To assure valid information at the ERROR pin, time must be allowed for the signal to propagate through the drivers (B to A), through the parity check circuitry (same as A to PARITY), and to the ERROR output.
 Valid data at the ERROR pin ≥ (B to A) + (A to PARITY).

AC WAVEFORMS

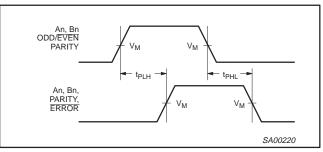
NOTE: For all waveforms, V_M = 1.5 V.



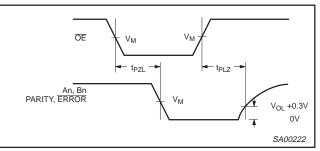
Waveform 1. Propagation delay for inverting output



Waveform 3. 3-State Output Enable time to HIGH level and Output Disable time from HIGH level



Waveform 2. Propagation delay For non-inverting output

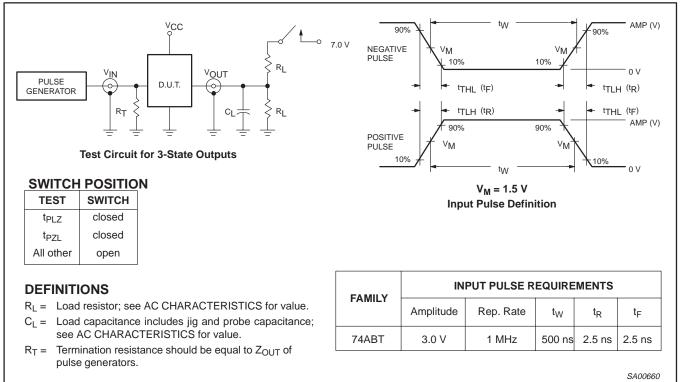


Waveform 4. 3-State Output Enable time to LOW level and Output Disable time from LOW level

Product data sheet

74ABT657

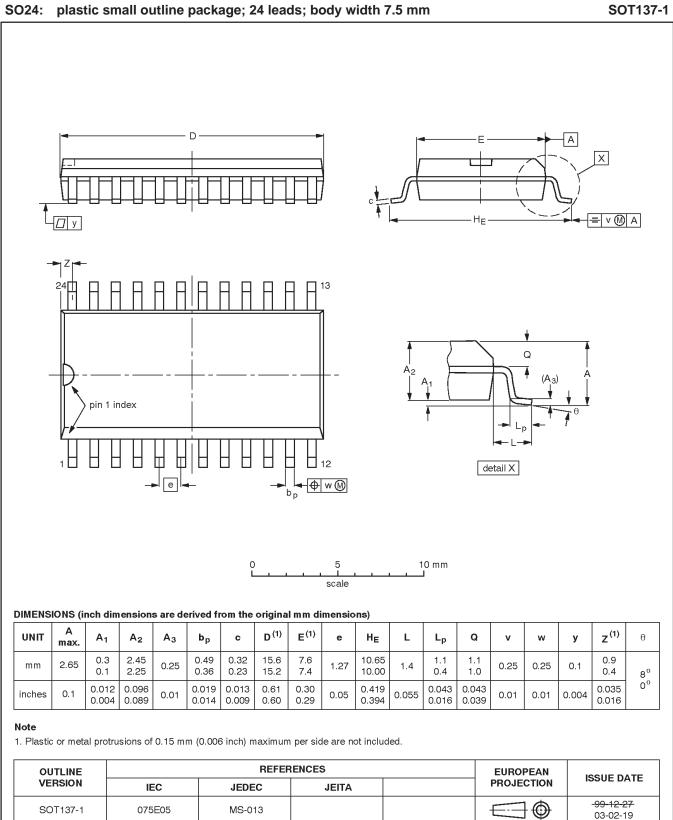
TEST CIRCUIT AND WAVEFORM



2004 Oct 27

74ABT657

Product data sheet

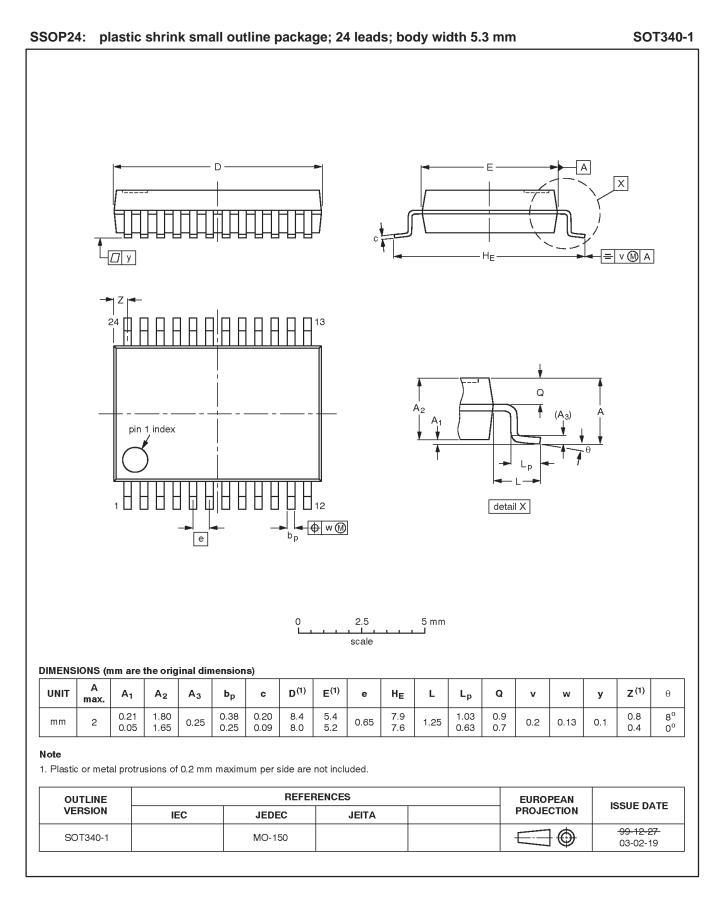


2004 Oct 27

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74ABT657

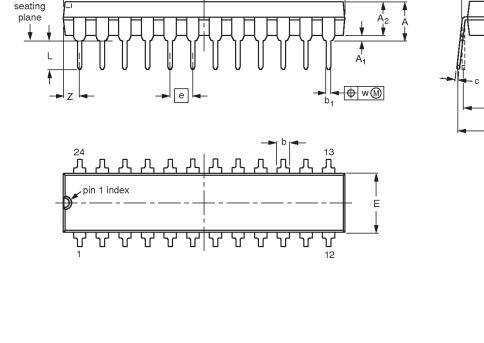
Product data sheet



2004 Oct 27

DIP24:

plastic dual in-line package; 24 leads (300 mil)



5 10 mm 0 scale

DIMENSIONS (mm dimensions are derived from the original inch dimensions)

U	TIV	A max.	A ₁ min.	A ₂ max.	b	b ₁	с	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	М _Н	w	Z ⁽¹⁾ max.
m	m	4.7	0.38	3.94	1.63 1.14	0.56 0.43	0.36 0.25	31.9 31.5	6.73 6.25	2.54	7.62	3.51 3.05	8.13 7.62	10.03 7.62	0.25	2.05
inc	hes	0.185	0.015	0.155	0.064 0.045	0.022 0.017	0.014 0.010	1.256 1.240	0.265 0.246	0.1	0.3	0.138 0.120	0.32 0.30	0.395 0.300	0.01	0.081

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	ENCES			
VERSION	IEC	JEDEC	JEITA		PROJECTION	1550E DATE
SOT222-1		MS-001				-99-12-27- 03-03-12

SOT222-1

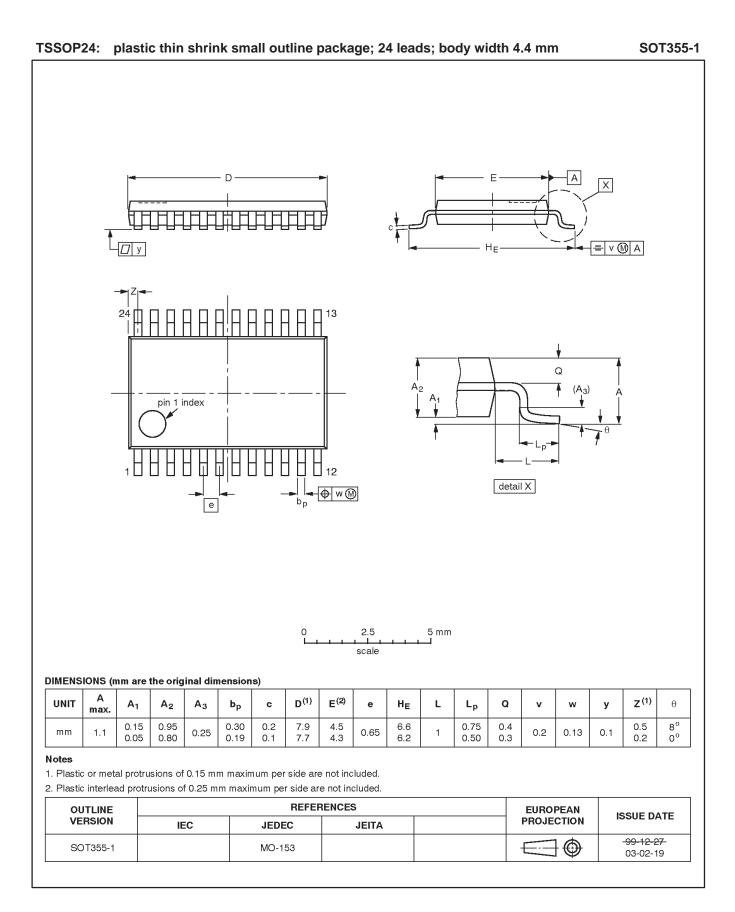
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Product data sheet

74ABT657



74ABT657

REVISION HISTORY

Rev	Date	Description
_2	20041027	Product data sheet (9397 750 14239). Supersedes data of 1995 Dec 11.
		Modifications:
		Ordering information table on page 2:
		 Removed "North America" column; renamed column "Outside North America" to "Order Code"
		AC Characteristics table on page 7:
		 Propagation delay An to Bn or Bn to An
		$T_{amb} = 25 \text{ °C}; V_{CC} = +5.0 \text{ V}:$
		changed t _{PLH(typ)} from 3.3 ns to 2.5 ns; t _{PLH(max)} changed from 5.0 ns to 4.1 ns
		changed t _{PHL(max)} from 4.3 ns to 3.9 ns
		$T_{amb} = -40 \text{ °C to } +85 \text{ °C; } V_{CC} = +5.0 \text{ V} \pm 10 \text{ %;}$
		changed t _{PLH(max)} from 5.5 ns to 4.6 ns; changed t _{PHL(max)} from 4.8 ns to 4.3 ns
		- Propagation delay An to PARITY
		T _{amb} = 25 °C; V _{CC} = +5.0 V: changed t _{PLH(tvp)} from 6.5 ns to 5.1 ns; t _{PLH(max)} changed from 8.7 ns to 6.7 ns
		changed $t_{PHL(typ)}$ from 7.0 ns to 5.0 ns; changed $t_{PHL(max)}$ from 9.1 ns to 7.4 ns
		$T_{amb} = -40 \text{ °C to } +85 \text{ °C; } V_{CC} = +5.0 \text{ V} \pm 10 \text{ %:}$
		changed t _{PLH(max)} from 10.1 ns to 8.1 ns; changed t _{PHL(max)} from 10.6 ns to 8.9 ns
		 Propagation delay ODD/EVEN to PARITY, ERROR
		T _{amb} = 25 °C; V _{CC} = +5.0 V:
		changed $t_{PLH(typ)}$ from 5.0 ns to 3.5 ns; $t_{PLH(max)}$ changed from 6.6 ns to 4.6 ns
		changed t _{PHL(typ)} from 5.0 ns to 3.7 ns; changed t _{PHL(max)} from 6.6 ns to 5.1 ns
		$T_{amb} = -40 \text{ °C to } +85 \text{ °C; } V_{CC} = +5.0 \text{ V} \pm 10 \text{ %:}$ changed $t_{PLH(max)}$ from 7.3 ns to 5.3 ns; changed $t_{PHL(max)}$ from 7.3 ns to 5.8 ns
		 Propagation delay Bn to ERROR
		$T_{amb} = 25 \text{ °C}; V_{CC} = +5.0 \text{ V}:$
		changed t _{PLH(typ)} from 9.2 ns to 7.3 ns; t _{PLH(max)} changed from 11.7 ns to 10.2 ns
		changed t _{PHL(typ)} from 9.6 ns to 7.9 ns; changed t _{PHL(max)} from 12.1 ns to 10.5 ns
		$T_{amb} = -40 \text{ °C to } +85 \text{ °C}; V_{CC} = +5.0 \text{ V} \pm 10 \text{ \%}:$
		changed t _{PLH(max)} from 13.8 ns to 12.3 ns; changed t _{PHL(max)} from 14.5 ns to 12.9 ns
		- Propagation delay PARITY to ERROR
		$T_{amb} = 25 \text{ °C}; V_{CC} = +5.0 \text{ V};$
		changed $t_{PLH(typ)}$ from 6.0 ns to 4.5 ns; $t_{PLH(max)}$ changed from 7.6 ns to 5.9 ns changed $t_{PHL(typ)}$ from 6.4 ns to 5.2 ns; changed $t_{PHL(max)}$ from 8.0 ns to 6.7 ns
		$T_{amb} = -40 \text{ °C to } +85 \text{ °C; } V_{CC} = +5.0 \text{ V} \pm 10 \text{ %;}$
		changed t _{PLH(max)} from 9.4 ns to 7.7 ns; changed t _{PHL(max)} from 9.4 ns to 8.1 ns
		- Output enable time to HIGH or LOW level
		$T_{amb} = 25 \text{ °C}; V_{CC} = +5.0 \text{ V}:$
		changed $t_{PZH(typ)}$ from 3.8 ns to 3.6 ns; $t_{PZH(max)}$ changed from 5.6 ns to 5.5 ns
		changed $t_{PZL(typ)}$ from 4.4 ns to 4.2 ns; changed $t_{PZL(max)}$ from 7.0 ns to 5.3 ns
		T _{amb} = −40 °C to +85 °C; V _{CC} = +5.0 V ± 10 %: changed t _{PZH(max)} from 6.6 ns to 6.5 ns; changed t _{PZL(max)} from 8.2 ns to 6.5 ns
		 Output disable time from HIGH or LOW level
		$T_{amb} = 25 \text{ °C}; V_{CC} = +5.0 \text{ V}:$
		changed t _{PHZ(tvp)} from 5.1 ns to 3.6 ns; t _{PHZ(max)} changed from 7.0 ns to 5.6 ns
		changed t _{PLZ(min)} from 2.7 ns to 2.2 ns; changed t _{PLZ(typ)} from 5.4 ns to 3.4 ns;
		changed t _{PLZ(max)} from 7.6 ns to 7.3 ns
		$T_{amb} = -40$ °C to +85 °C; $V_{CC} = +5.0$ V ± 10 %:
		changed t _{PHZ(max)} from 7.6 ns to 6.2 ns; changed t _{PLZ(min)} from 2.7 ns to 2.2 ns; changed t _{PLZ(max)} from 8.1 ns to 7.8 ns
		Added Revision History table.
_1	19951211	Product specification. ECN 853-1615 16106 of 11 December 1995.

Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2] [3]}	Definitions
I	Objective data sheet	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data sheet	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data sheet	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Disclaimers

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Contact information

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